POZNAN UNIVERSITY OF TECHNOLOGY



EUROPEAN CREDIT TRANSFER AND ACCUMULATION SYSTEM (ECTS)

pl. M. Skłodowskiej-Curie 5, 60-965 Poznań

COURSE DESCRIPTION CARD - SYLLABUS

Course name

Thin films II

Course

Field of study Year/Semester

Materials Science 1/2

Area of study (specialization) Profile of study

general academic

Level of study Course offered in

Second-cycle studies polish

Form of study Requirements

full-time elective

Number of hours

Lecture Laboratory classes Other (e.g. online)

15 15

Tutorials Projects/seminars

Number of credit points

2

Lecturers

Responsible for the course/lecturer:

Responsible for the course/lecturer:

dr hab. Izabela Szafraniak-Wiza, prof. PP

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tel. 61 665 3779

Faculty of Materials Engineering and Technical

Physics

Piotrowo 3 Street, 60-965 Poznań

Prerequisites

Knowledge: Basic knowledge of solid state physics, crystallography, materials science and

nanotechnology

Skills: Logical thinking, use of the information obtained from library and Internet

Social competencies: Understanding the need for learning and acquiring new knowledge

Course objective

The knowledge of specific methods of thin film depositions, specific properties of thin films and their investigation methods. The knowledge of thin films applications in electronics

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Course-related learning outcomes

Knowledge

The student has knowledge about specific properties of thin films.K_W04 K_W06 K_W08

The student has knowledge about specific investigation methods of thin film.K_W01, K_W04

The student has knowledge about thin film applications in modern electronics.K W06, K W04 K W07

Skills

The student can propose applications of different thin films in modern electronics. K U01 K U13

The student can propose and investigate the specific properties of thin films. K_U01 K_U08 nK_U10 K_U013

The student can relate the specific properties of thin films and their deposition methods. K_U08, K_U010 K_U016

Social competences

The student can collaborate in order to obtain and implement the new knowledge. K K03

The student is aware of importance of nanotechnology in modern industry and society. K_K02

Methods for verifying learning outcomes and assessment criteria

Learning outcomes presented above are verified as follows:

Lectures:

Written test at the end of the semester

Laboratory:

The final report prepared according to lecturer's guidelines, student activity at laboratory and final test.

Programme content

Lectures:

- 1. Thin film deposition methods
- 2. Thin films in modern electronics
- 3. True single crystalline thin films
- 4. Conventional and unconventional lithography
- 5. Specific methods of thin films investigations

Laboratory:

1. XRD investigations of thin films.

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- 2. AFM investigation of film topography part I
- 3. AFM investigation of film topography part II
- 4. Structural analysis of epitaxial films
- 5. Epitaxial stress analysis of thin films

Teaching methods

- 1. Lecture: multimedia presentation.
- 2. Laboratory exercises: performing exercises, discussion, team work.

Bibliography

Basic

- 1. Oleś, Metody doświadczalne fizyki ciała stałego, WNT 1998
- 2. Nanoelectronics and Information Technology, Waser R., Wiley-VCH, Berlin, 2003
- 3. Nanomateriały inżynierskie, K. Kurzydłowski, M. Lewandowska (red.), PWN 2010
- 4. Nanotechnologie, R.W. Kelsall, I.W. Hamley, M. Goeghegan (red.), PWN, 2008

Additional

Handbook of thin film devices, M. H. Francombe (red.), Acad. Press, San Diego, 2000

Kittel C., Wstęp do fizyki ciała stałego, PWN, Warszawa, 1999

Scientific papers

Breakdown of average student's workload

	Hours	ECTS
Total workload	68	2,0
Classes requiring direct contact with the teacher	33	1,0
Student's own work (literature studies, preparation for laboratory classes, preparation for colloquium) ¹	35	1,0

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¹ delete or add other activities as appropriate